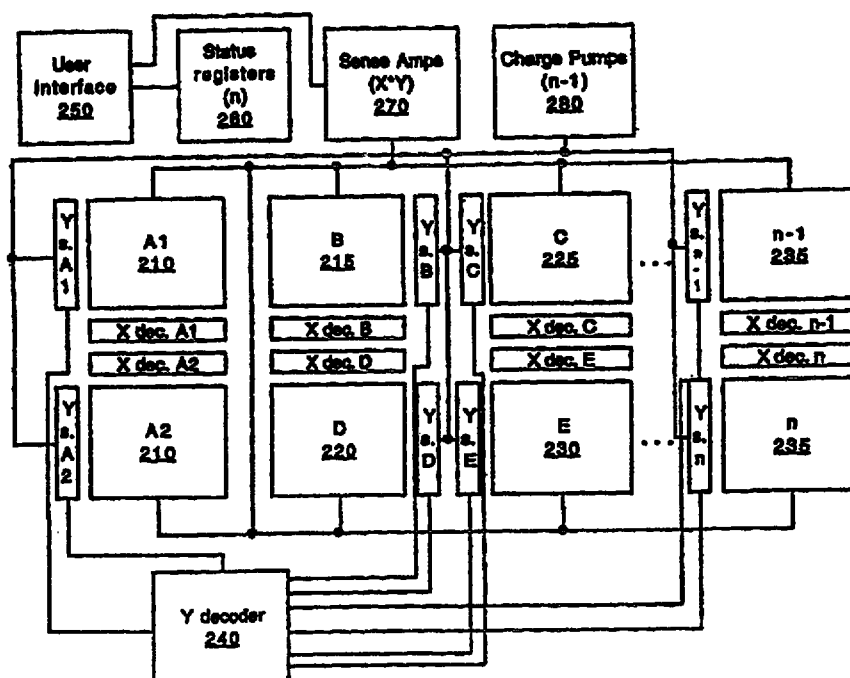




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(54) Title: FLASH MEMORY PARTITIONING FOR READ-WHILE-WRITE OPERATION



(57) Abstract

A method and apparatus for partitioning a flash memory device (20) is provided. The flash memory device includes a plurality of partitions, (210, 215, 220, 225, 230), each partition able to be read, written, or erased simultaneously with the other partitions.